

## LME49723 Dual High Fidelity Audio Operational Amplifier

Check for Samples: [LME49723](#)

### FEATURES

- Easily Drives 600Ω Loads
- Optimized for Superior Audio Signal Fidelity
- Output Short Circuit Protection
- PSRR and CMRR Exceed 100dB (typ)
- SOIC Package

### APPLICATIONS

- High Quality Audio Amplification
- High Fidelity Preamplifiers
- High Fidelity Multimedia
- Phono Pre Amps
- High Performance Professional Audio
- High Fidelity Equalization and Crossover Networks
- High Performance Line Drivers
- High Performance Line Receivers
- High Fidelity Active Filters

### KEY SPECIFICATIONS

- Power Supply Voltage Range:  $\pm 2.5$  to  $\pm 17$  V
- THD+N ( $A_V = 1$ ,  $V_{OUT} = 3V_{RMS}$ ,  $f_{IN} = 1$  kHz)
  - $R_L = 2k\Omega$ : 0.0002 % (typ)
  - $R_L = 600\Omega$ : 0.0002 % (typ)
- Input Noise Density: 3.6 nV/ $\sqrt{Hz}$  (typ)
- Slew Rate:  $\pm 8$  V/ $\mu s$  (typ)
- Gain Bandwidth Product: 17 MHz (typ)
- Open Loop Gain ( $R_L = 600\Omega$ ): 105 dB (typ)
- Input Bias Current: 200 nA (typ)
- Input Offset Voltage: 0.3 mV (typ)

### DESCRIPTION

The LME49723 is part of the ultra-low distortion, low noise, high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49723 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49723 combines extremely low voltage noise density (3.6nV/ $\sqrt{Hz}$ ) with vanishingly low THD+N (0.0002%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49723 has a high slew rate of  $\pm 20$ V/ $\mu s$  and an output current capability of  $\pm 26$ mA. Further, dynamic range is maximized by an output stage that drives 2kΩ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads.

The LME49723's outstanding CMRR (100dB), PSRR (100dB), and  $V_{OS}$  (0.3mV) give the amplifier excellent operational amplifier DC performance.

The LME49723 has a wide supply range of  $\pm 2.5$ V to  $\pm 17$ V. Over this supply range the LME49723's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49723 is unity gain stable.

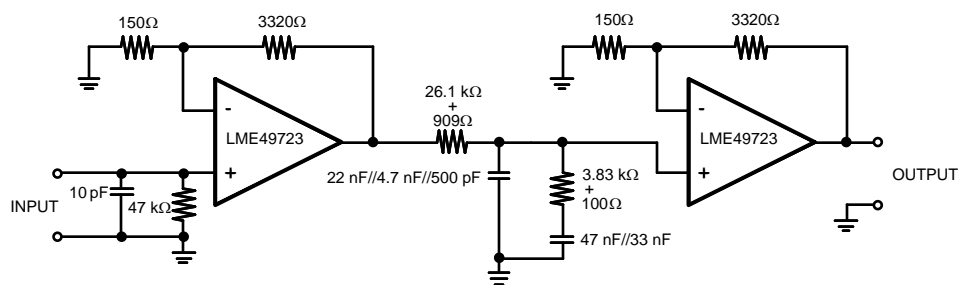
The LME49723 is available in an 8-lead narrow body SOIC package. Demonstration boards are available for each package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

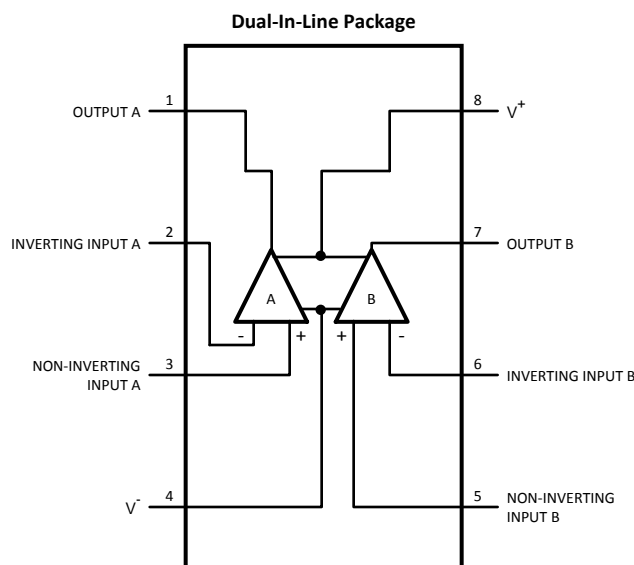
## TYPICAL APPLICATION



Note: 1% metal film resistors, 5% polypropylene capacitors

**Figure 1. Passively Equalized RIAA Phono Preamplifier**

## CONNECTION DIAGRAM



**Figure 2. SOIC Package  
See Package Number D0008A**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**ABSOLUTE MAXIMUM RATINGS<sup>(1)(2)(3)</sup>**

Power Supply Voltage ( $V_S = V^+ - V^-$ )	36V
Storage Temperature	–65°C to 150°C
Input Voltage	(V–) - 0.7V to (V+) + 0.7V
Output Short Circuit <sup>(4)</sup>	Continuous
Power Dissipation	Internally Limited
ESD Susceptibility <sup>(5)</sup>	800V
ESD Susceptibility <sup>(6)</sup>	180V
Junction Temperature	150°C
Thermal Resistance $\theta_{JA}$ (SO)	145°C/W
Temperature Range $T_{MIN} \leq T_A \leq T_{MAX}$	–40°C $\leq T_A \leq$ 85°C
Supply Voltage Range	$\pm 2.5V \leq V_S \leq \pm 17V$

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.
- (2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (4) Amplifier output connected to GND, any number of amplifiers within a package.
- (5) Human body model, 100pF discharged through a 1.5k $\Omega$  resistor.
- (6) Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50 $\Omega$ ).

**ELECTRICAL CHARACTERISTICS FOR THE LME49723<sup>(1)(2)</sup>**

The specifications apply for  $V_S = \pm 15V$ ,  $R_L = 2k\Omega$ ,  $f_{IN} = 1kHz$ ,  $T_A = 25^\circ C$ , unless otherwise specified.

Symbol	Parameter	Conditions		LME49723		Units (Limits)
				Typical <sup>(3)</sup>	Limit <sup>(4)</sup>	
THD+N	Total Harmonic Distortion + Noise	$A_V = 1$ , $V_{OUT} = 3V_{rms}$ $R_L = 2k\Omega$ $R_L = 600\Omega$		0.0002 0.0002	0.0004	% (max)
IMD	Intermodulation Distortion	$A_V = 1$ , $V_{OUT} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1		0.0005		%
GBWP	Gain Bandwidth Product			19	15	MHz (min)
SR	Slew Rate			$\pm 8$	$\pm 6$	V/ $\mu s$ (min)
FPBW	Full Power Bandwidth	$V_{OUT} = 1V_{P-P}$ , –3dB referenced to output magnitude at $f = 1kHz$		4		MHz
$e_n$	Equivalent Input Noise Voltage	$f_{BW} = 20Hz$ to 20kHz		0.45	0.65	$\mu V_{RMS}$ (max)
	Equivalent Input Noise Density	$f = 1kHz$ $f = 10Hz$		3.2 8.5	5	nV/ $\sqrt{Hz}$ (max)
$i_n$	Current Noise Density	$f = 1kHz$ $f = 10Hz$		0.7 1.3		pA/ $\sqrt{Hz}$
$V_{OS}$	Offset Voltage			$\pm 0.3$	1	mV (max)
$\Delta V_{OS}/\Delta T_{mp}$	Average Input Offset Voltage Drift vs Temperature	–40°C $\leq T_A \leq$ 85°C		0.2		$\mu V/^\circ C$
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$\Delta V_S = 20V^{(5)}$		100	95	dB (min)
ISO <sub>CH-CH</sub>	Channel-to-Channel Isolation	$f_{IN} = 1kHz$ $f_{IN} = 20kHz$		118 112		dB
$I_B$	Input Bias Current	$V_{CM} = 0V$		200	300	nA (max)

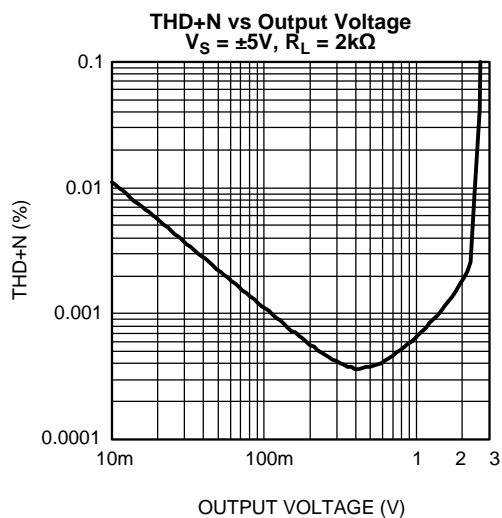
- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.
- (2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (3) Typical specifications are specified at +25°C and represent the most likely parametric norm.
- (4) Tested limits are specified to AOQL (Average Outgoing Quality Level).
- (5) PSRR is measured as follows:  $V_{OS}$  is measured at two supply voltages,  $\pm 5V$  and  $\pm 15V$ .  $PSRR = |20\log(\Delta V_{OS}/\Delta V_S)|$ .

**ELECTRICAL CHARACTERISTICS FOR THE LME49723<sup>(1)(2)</sup> (continued)**

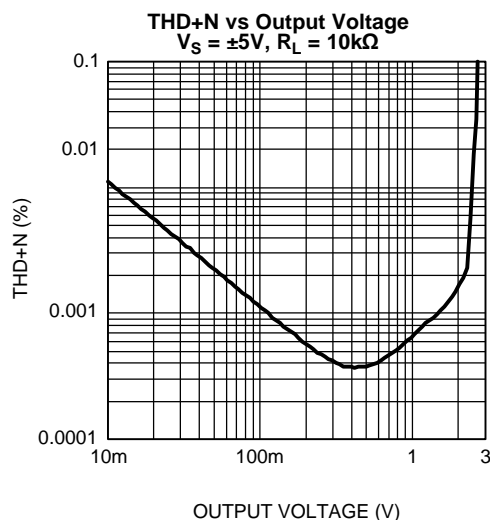
The specifications apply for  $V_S = \pm 15V$ ,  $R_L = 2k\Omega$ ,  $f_{IN} = 1kHz$ ,  $T_A = 25^\circ C$ , unless otherwise specified.

Symbol	Parameter	Conditions	LME49723		Units (Limits)
			Typical <sup>(3)</sup>	Limit <sup>(4)</sup>	
$\Delta I_{OS}/\Delta T_{e_{mp}}$	Input Bias Current Drift vs Temperature	$-40^\circ C \leq T_A \leq 85^\circ C$	0.1		nA/ $^\circ C$
$I_{OS}$	Input Offset Current	$V_{CM} = 0V$	7	100	nA (max)
$V_{IN-CM}$	Common-Mode Input Voltage Range		$\pm 14$	$(V+) - 2.0$ $(V-) + 2.0$	V (min)
CMRR	Common-Mode Rejection	$-10V < V_{cm} < 10V$	100	90	dB (min)
$Z_{IN}$	Differential Input Impedance		30		k $\Omega$
	Common Mode Input Impedance	$-10V < V_{cm} < 10V$	1000		M $\Omega$
$A_{VOL}$	Open Loop Voltage Gain	$-10V < V_{out} < 10V$ , $R_L = 600\Omega$	100	98	dB (min)
		$-10V < V_{out} < 10V$ , $R_L = 2k\Omega$	105		
		$-10V < V_{out} < 10V$ , $R_L = 10k\Omega$	105		
$V_{OUTMAX}$	Maximum Output Voltage Swing	$R_L = 600\Omega$	$\pm 13.5$	$\pm 12.5$	V (min)
		$R_L = 2k\Omega$	$\pm 14.0$		
		$R_L = 10k\Omega$	$\pm 14.1$		
$I_{OUT}$	Output Current	$R_L = 600\Omega$ , $V_S = \pm 17V$	$\pm 25$	$\pm 21$	mA (min)
$I_{OUT-CC}$	Instantaneous Short Circuit Current		+53 -42		mA
$R_{OUT}$	Output Impedance	$f_{IN} = 10kHz$ Closed-Loop Open-Loop	0.01 13		$\Omega$
$C_{LOAD}$	Capacitive Load Drive Overshoot	100pF	16		%
$I_S$	Total Quiescent Current	$I_{OUT} = 0mA$	6.7	7.5	mA (max)

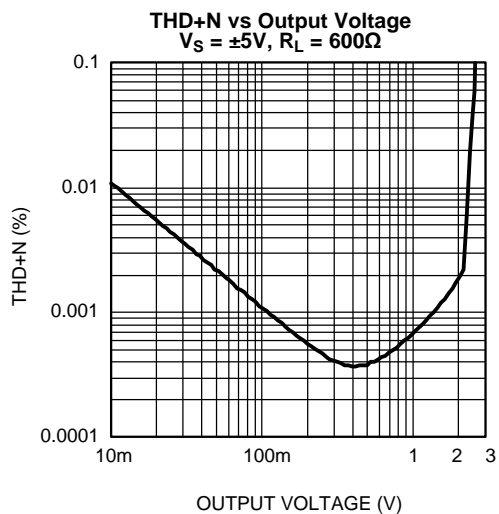
## TYPICAL PERFORMANCE CHARACTERISTICS



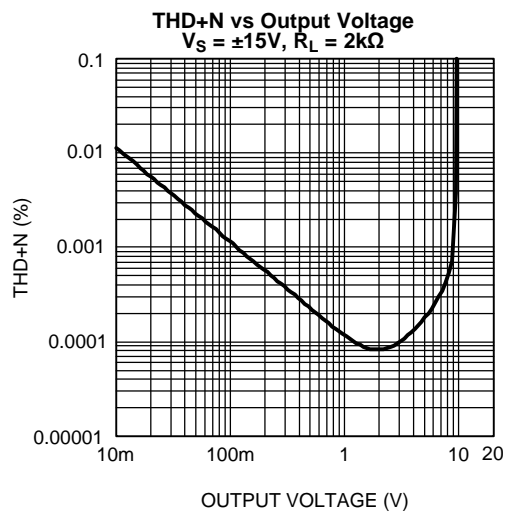
**Figure 3.**



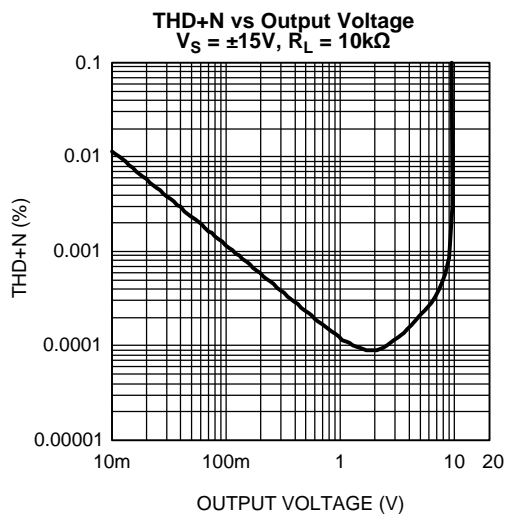
**Figure 4.**



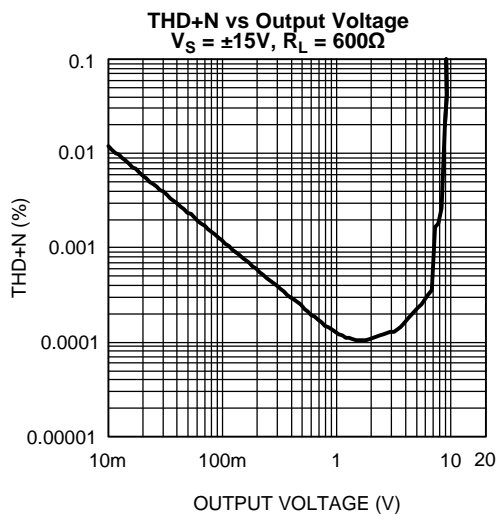
**Figure 5.**



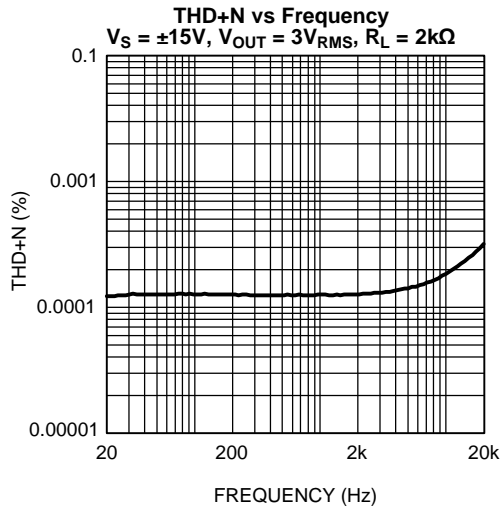
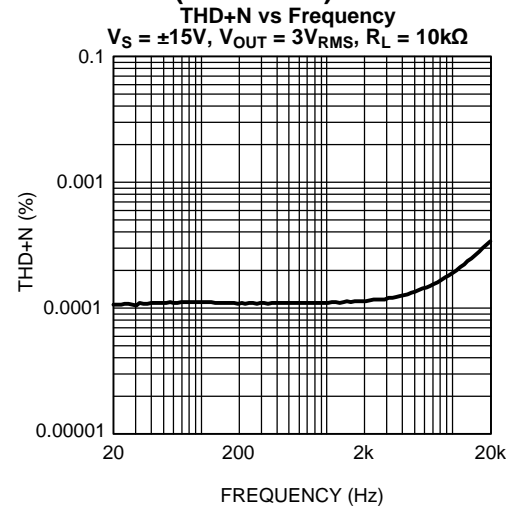
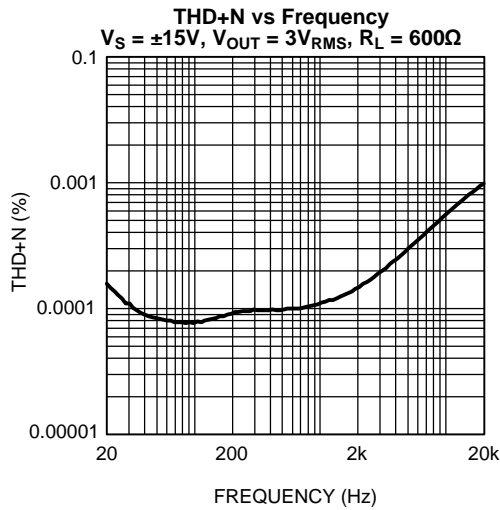
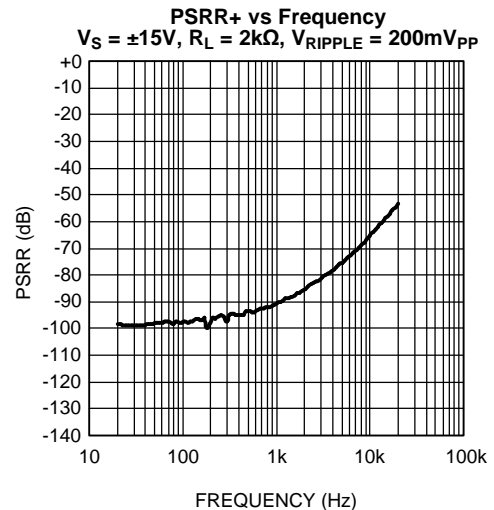
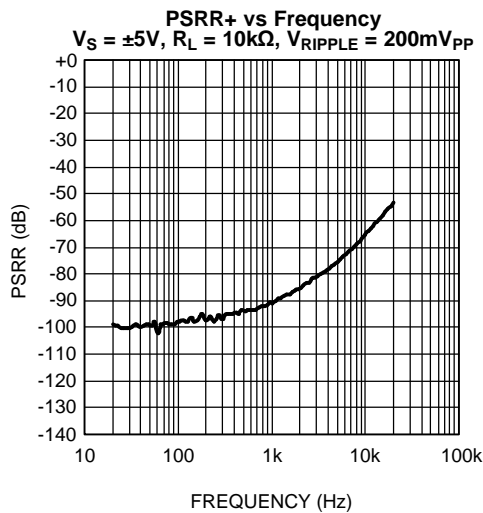
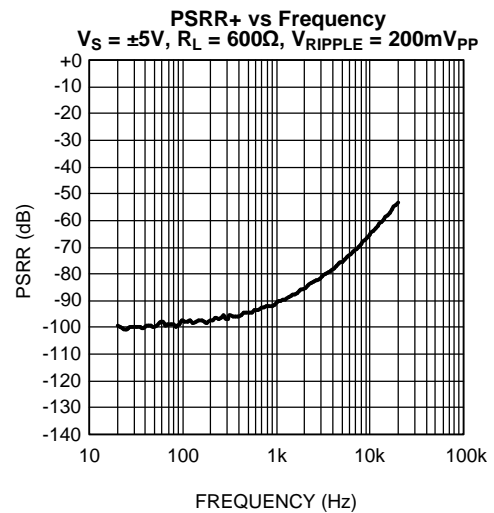
**Figure 6.**



**Figure 7.**



**Figure 8.**

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)****Figure 9.****Figure 10.****Figure 11.****Figure 12.****Figure 13.****Figure 14.**

## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

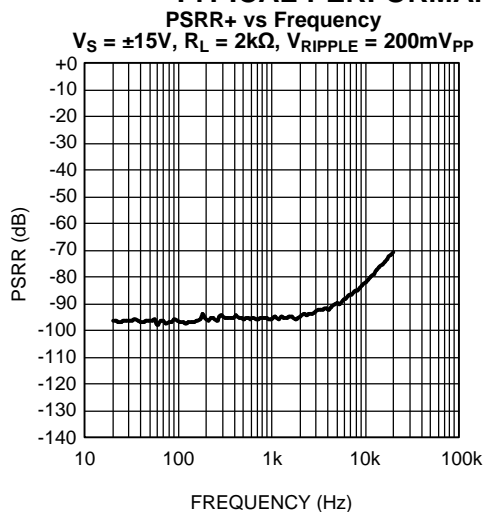


Figure 15.

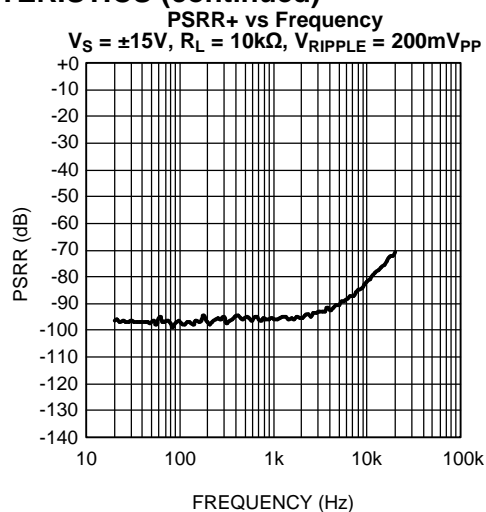


Figure 16.

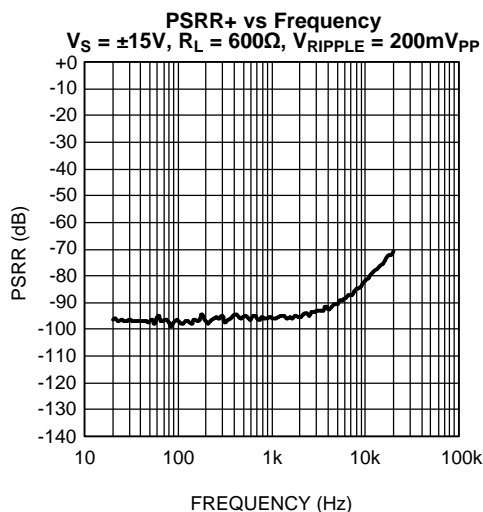


Figure 17.

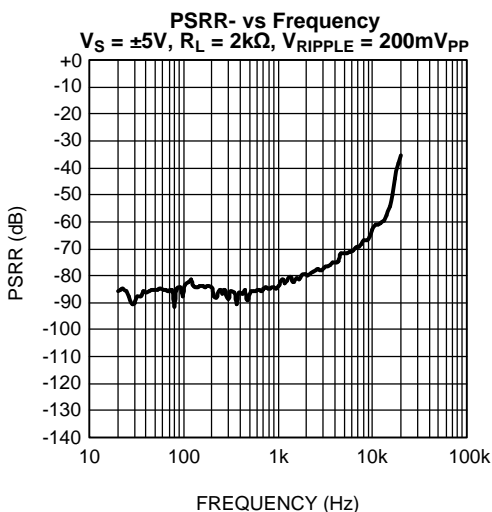


Figure 18.

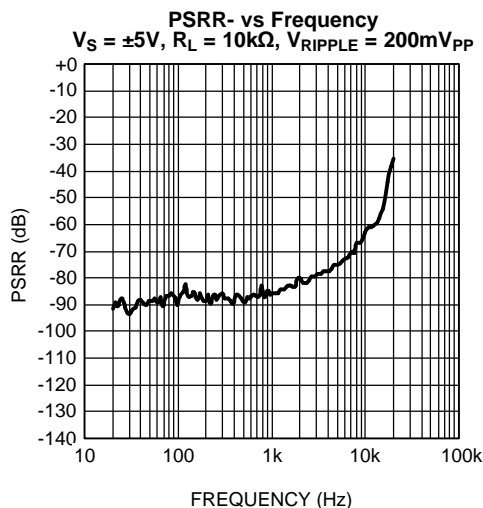


Figure 19.

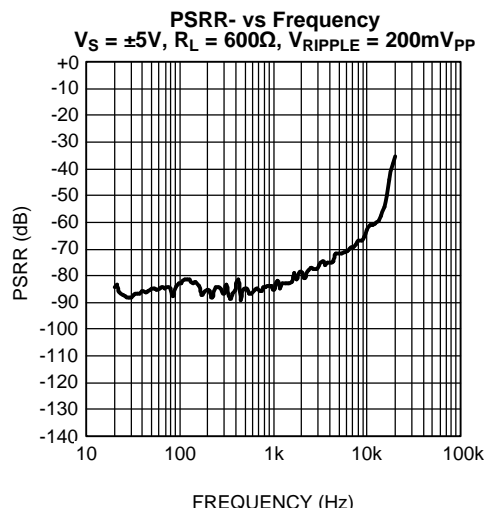
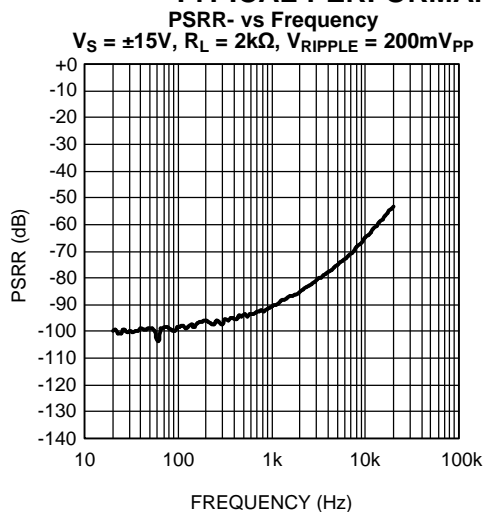
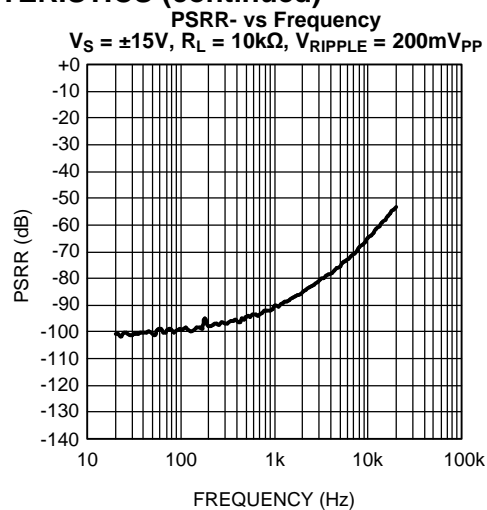
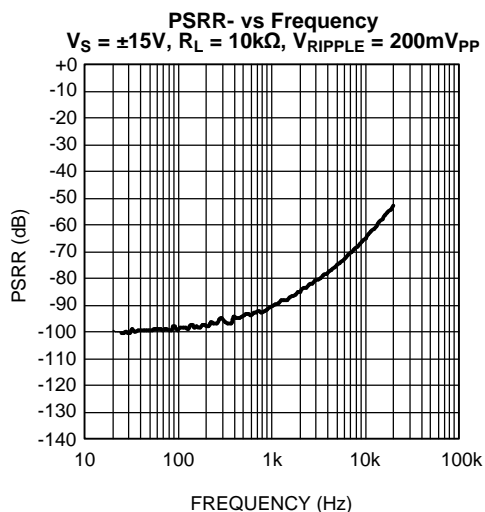
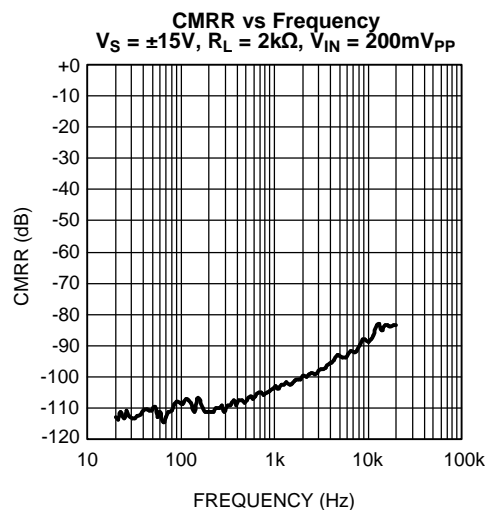
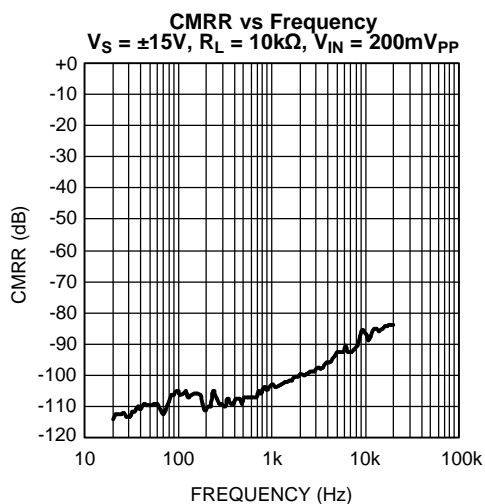
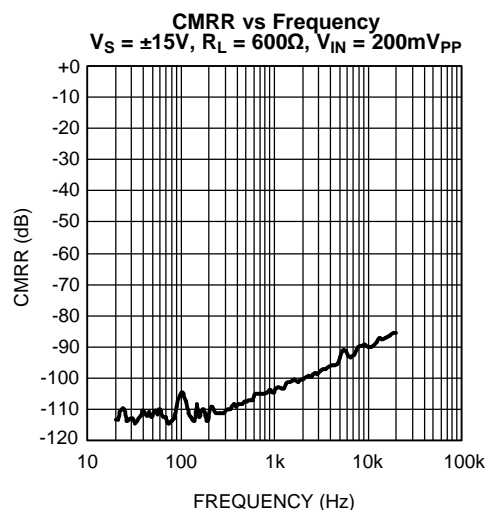


Figure 20.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)****Figure 21.****Figure 22.****Figure 23.****Figure 24.****Figure 25.****Figure 26.**



## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

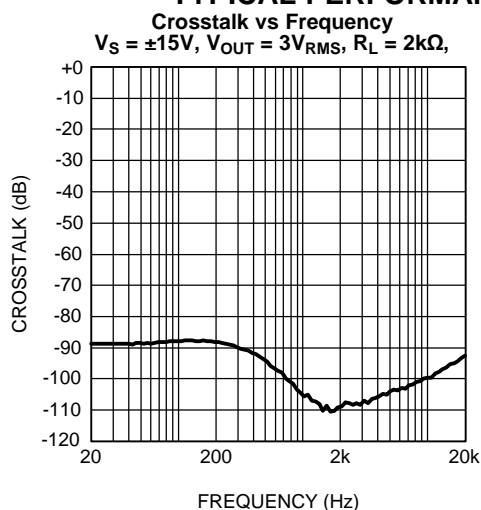


Figure 27.

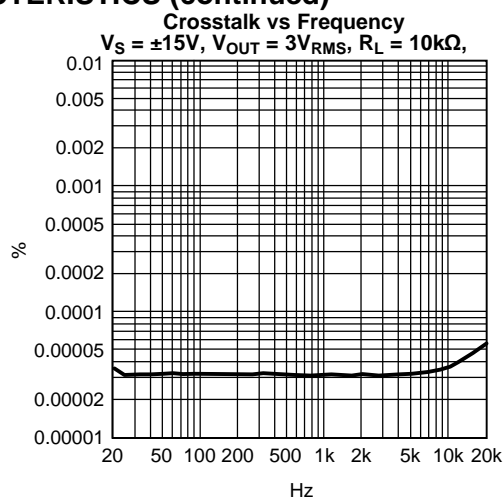


Figure 28.

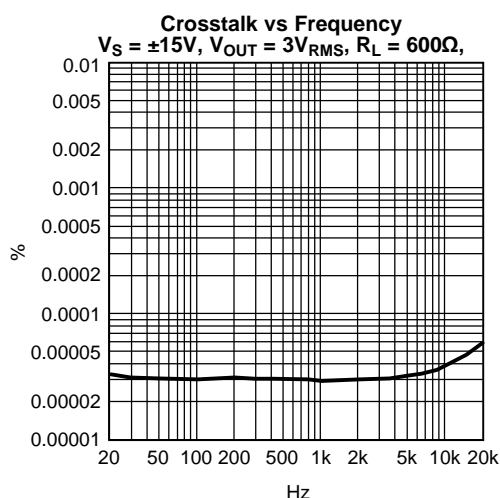


Figure 29.

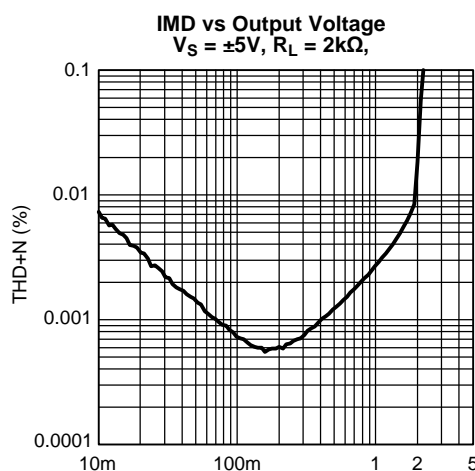


Figure 30.

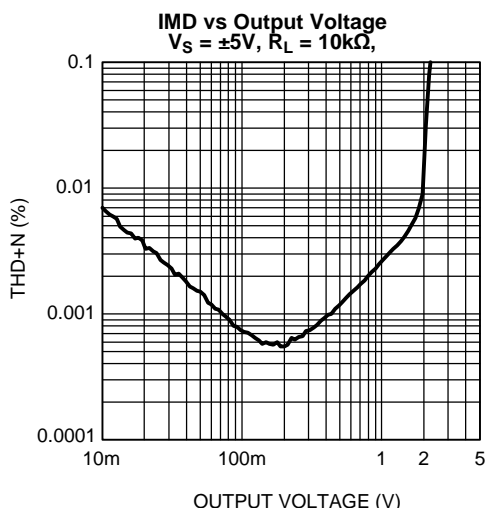


Figure 31.

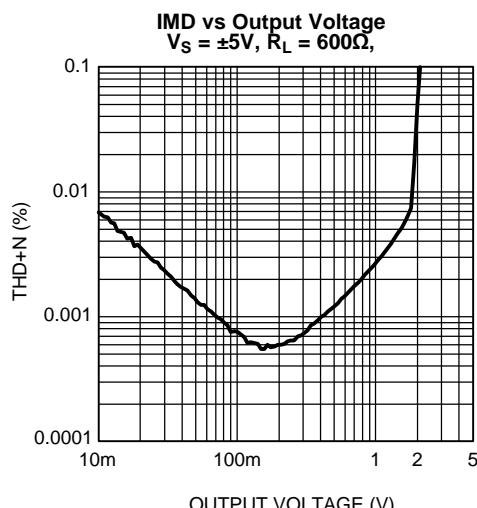
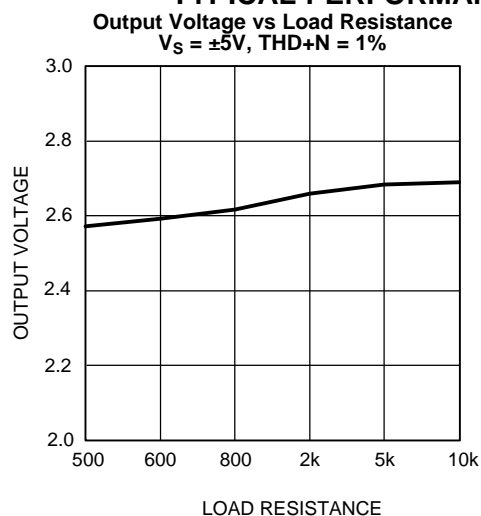
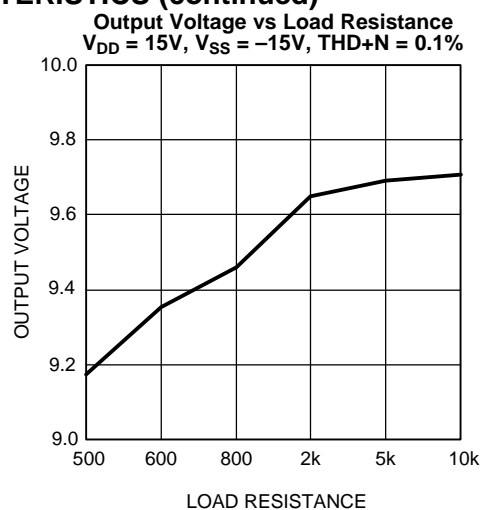
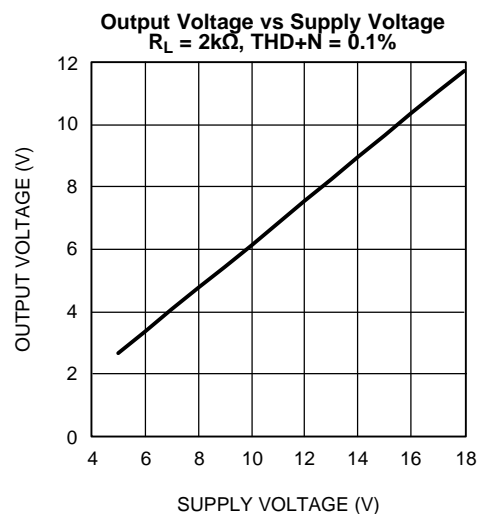
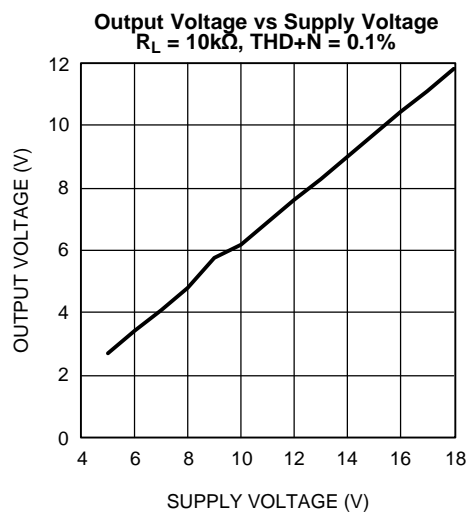
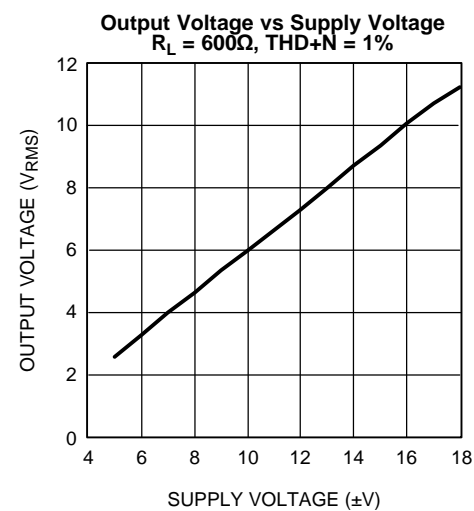
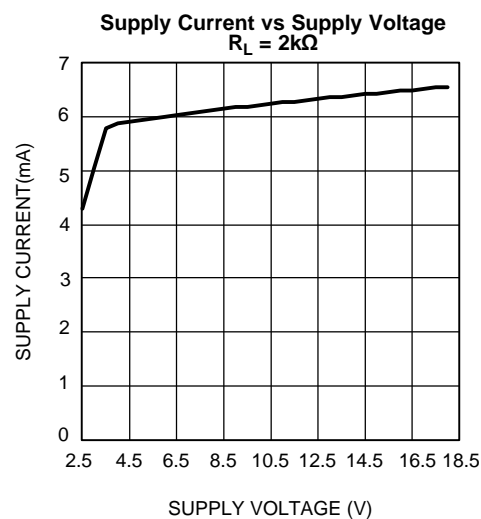


Figure 32.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)****Figure 33.****Figure 34.****Figure 35.****Figure 36.****Figure 37.****Figure 38.**

## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

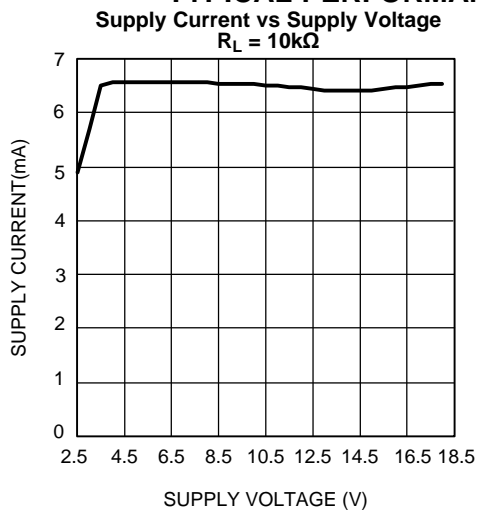


Figure 39.

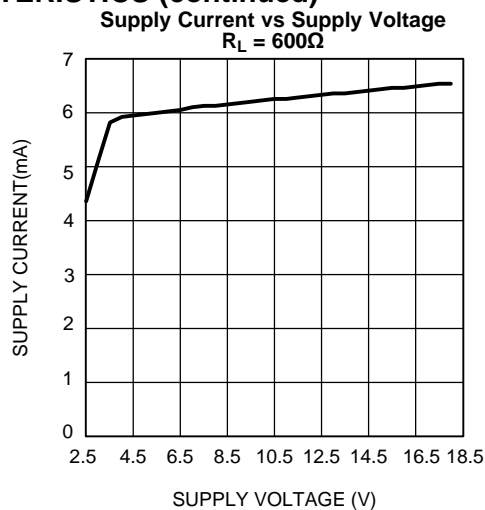
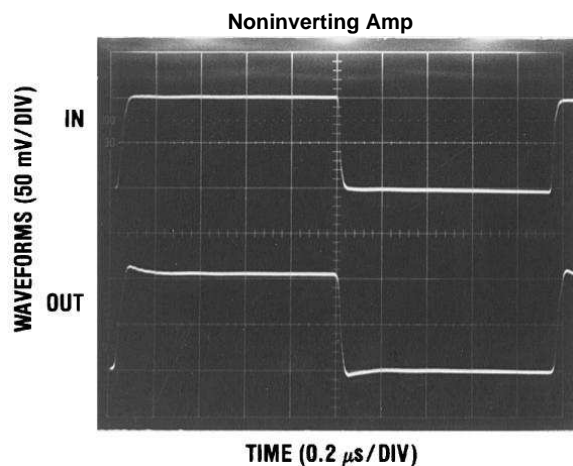
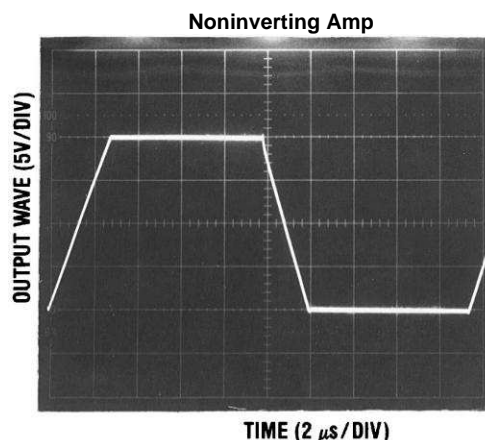


Figure 40.



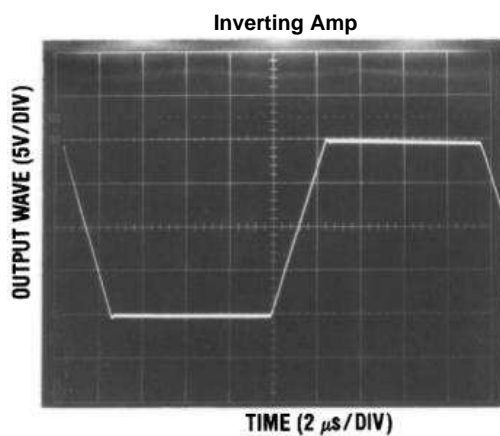
TIME (0.2  $\mu$ s/DIV)

Figure 41.



TIME (2  $\mu$ s/DIV)

Figure 42.



TIME (2  $\mu$ s/DIV)

Figure 43.

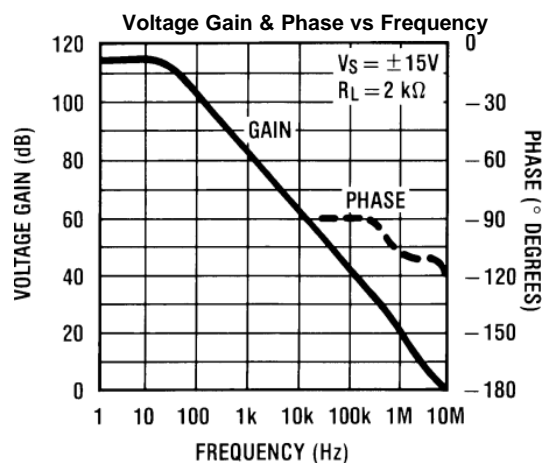


Figure 44.

## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

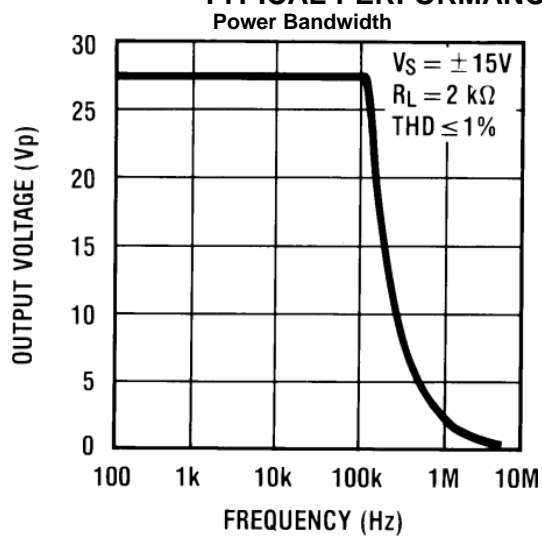


Figure 45.

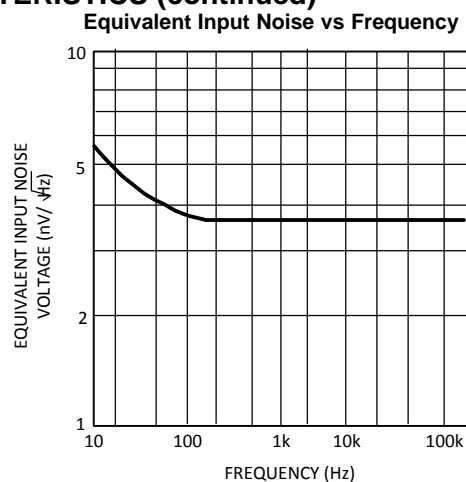


Figure 46.

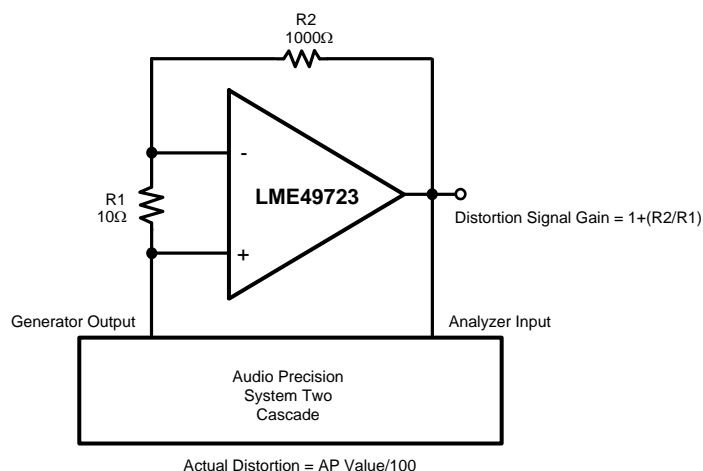
## APPLICATION INFORMATION

### DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LME49723 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49723's low residual distortion is an input referred internal error. As shown in Figure 47, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 47.

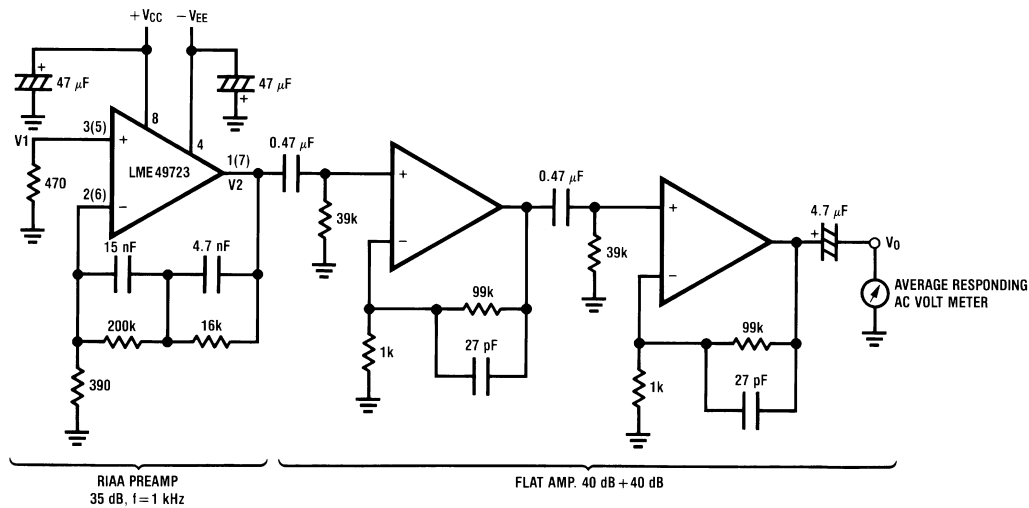
This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.



**Figure 47. THD+N and IMD Distortion Test Circuit**

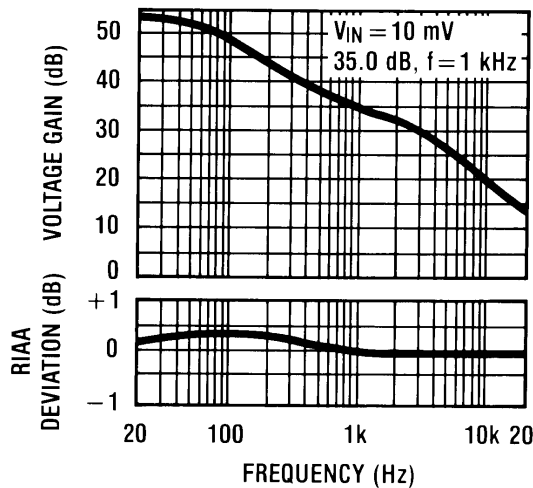
The LME49723 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

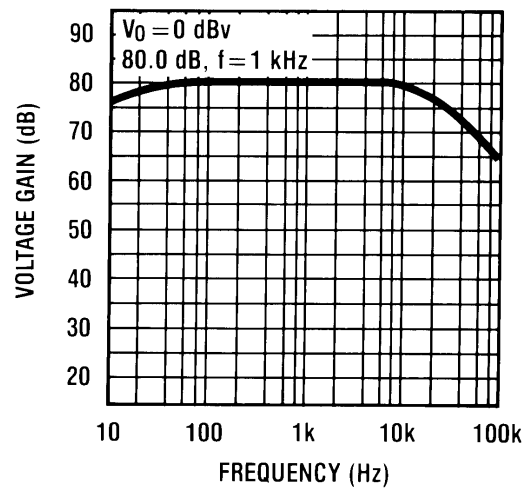


Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.

**Figure 48. Noise Measurement Circuit Total Gain: 115 dB @  $f = 1$  kHz**  
**Input Referred Noise Voltage:  $e_n = V_0/560,000$  (V)**

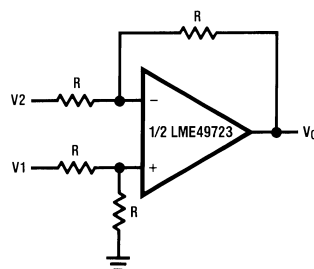


**Figure 49. RIAA Preamp Voltage Gain,  
RIAA Deviation vs Frequency**



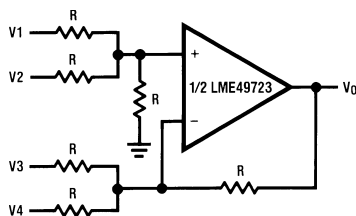
**Figure 50. Flat Amp Voltage Gain vs Frequency**

## TYPICAL APPLICATIONS



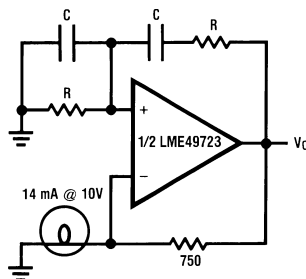
$$V_O = V_1 - V_2$$

**Figure 51. Balanced to Single Ended Converter**



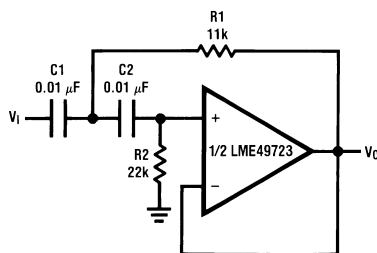
$$V_O = V_1 + V_2 - V_3 - V_4$$

**Figure 52. Adder/Subtractor**



$$f_o = \frac{1}{2\pi RC}$$

**Figure 53. Sine Wave Oscillator**



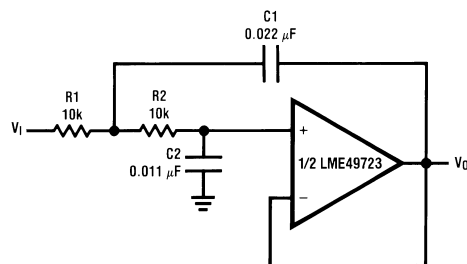
if  $C_1 = C_2 = C$

$$R_1 = \frac{\sqrt{2}}{2\omega_o C}$$

$$R_2 = 2 \cdot R_1$$

Illustration is  $f_o = 1 \text{ kHz}$

**Figure 54. Second Order High Pass Filter (Butterworth)**



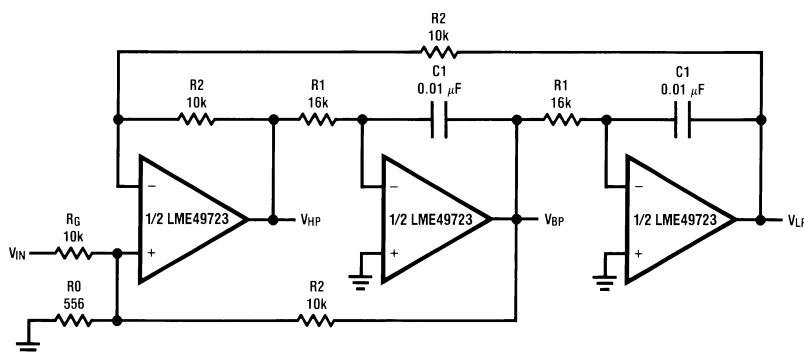
if  $R_1 = R_2 = R$

$$C_1 = \frac{\sqrt{2}}{\omega_0 R}$$

$$C_2 = \frac{C_1}{2}$$

Illustration is  $f_0 = 1 \text{ kHz}$

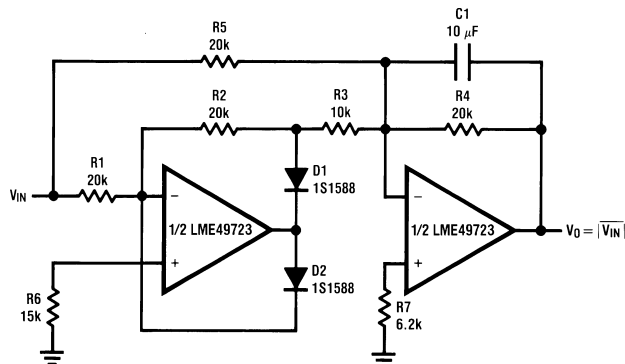
**Figure 55. Second Order Low Pass Filter (Butterworth)**



$$f_0 = \frac{1}{2\pi C_1 R_1}, Q = \frac{1}{2} \left( 1 + \frac{R_2}{R_0} + \frac{R_2}{R_G} \right), A_{BP} = Q A_{LP} = Q A_{LH} = \frac{R_2}{R_G}$$

Illustration is  $f_0 = 1 \text{ kHz}$ ,  $Q = 10$ ,  $A_{BP} = 1$

**Figure 56. State Variable Filter**



**Figure 57. AC/DC Converter**



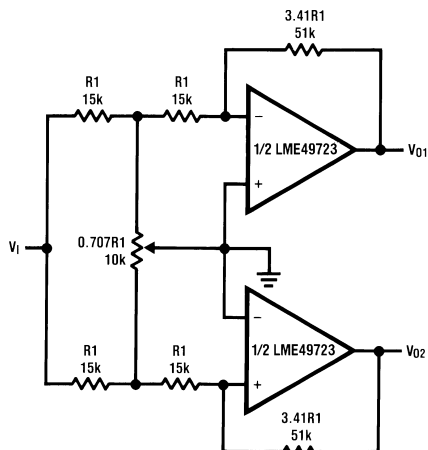


Figure 58. 2 Channel Panning Circuit (Pan Pot)

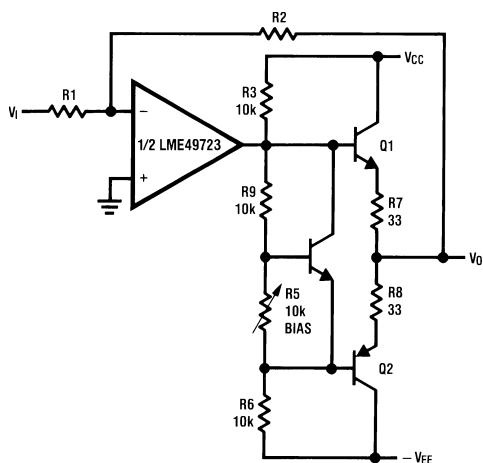
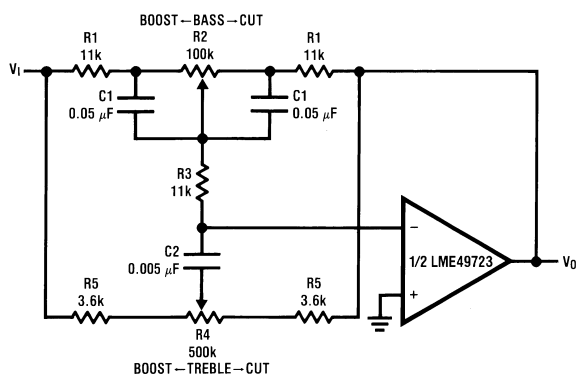


Figure 59. Line Driver



$$f_L = \frac{1}{2\pi R_2 C_1}, f_{LB} = \frac{1}{2\pi R_1 C_1}$$

$$f_H = \frac{1}{2\pi R_5 C_2}, f_{HB} = \frac{1}{2\pi (R_1 + R_5 + 2R_3) C_2}$$

Illustration is:

$$f_L = 32 \text{ Hz}, f_{LB} = 320 \text{ Hz}$$

$$f_H = 11 \text{ kHz}, f_{HB} = 1.1 \text{ kHz}$$

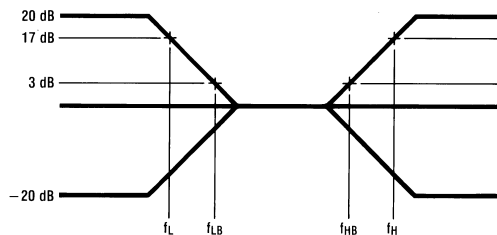
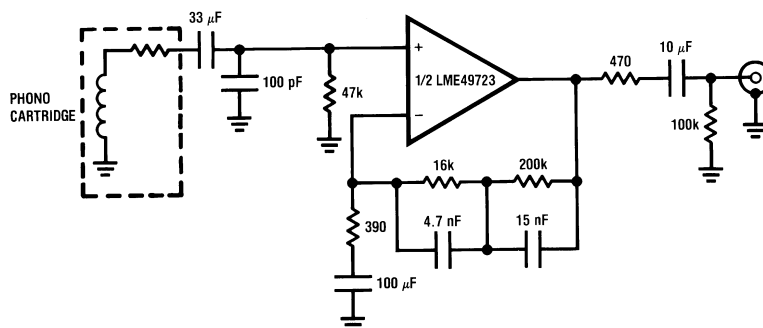
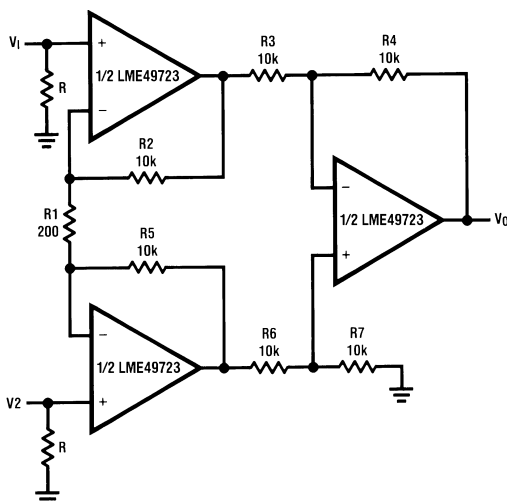


Figure 60. Tone Control



$A_v = 35 \text{ dB}$   
 $E_n = 0.33 \mu\text{V}$   
 $S/N = 90 \text{ dB}$   
 $f = 1 \text{ kHz}$   
 A Weighted  
 A Weighted,  $V_{IN} = 10 \text{ mV}$   
 @  $f = 1 \text{ kHz}$

Figure 61. RIAA Preamp



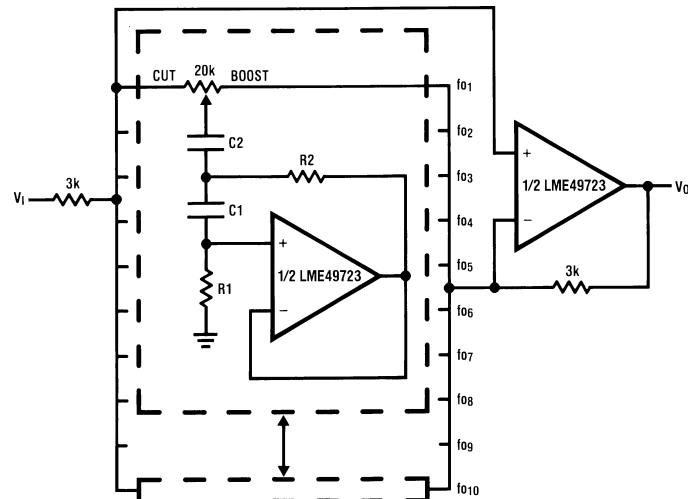
If  $R_2 = R_5$ ,  $R_3 = R_6$ ,  $R_4 = R_7$

$$V_0 = \left(1 + \frac{2R_2}{R_1}\right) \frac{R_4}{R_3} (V_2 - V_1)$$

Illustration is:

$$V_0 = 101(V_2 - V_1)$$

Figure 62. Balanced Input Mic Amp



**Figure 63. Band Graphic Equalizer**

fo (Hz)	C <sub>1</sub>	C <sub>2</sub>	R <sub>1</sub>	R <sub>2</sub>
32	0.12μF	4.7μF	75kΩ	500Ω
64	0.056μF	3.3μF	68kΩ	510Ω
125	0.033μF	1.5μF	62kΩ	510Ω
250	0.015μF	0.82μF	68kΩ	470Ω
500	8200pF	0.39μF	62kΩ	470Ω
1k	3900pF	0.22μF	68kΩ	470Ω
2k	2000pF	0.1μF	68kΩ	470Ω
4k	1100pF	0.056μF	62kΩ	470Ω
8k	510pF	0.022μF	68kΩ	510Ω
16k	330pF	0.012μF	51kΩ	510Ω

**REVISION HISTORY**

Rev	Date	Description
1.0	01/07/08	Initial release.
1.01	02/11/08	Text edits.
B	04/04/13	Changed layout of National Data Sheet to TI format.

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LME49723MA/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	L49723 MA	<a href="#">Samples</a>
LME49723MAX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	L49723 MA	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49723MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LME49723MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0



## TUBE



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LME49723MA/NOPB	D	SOIC	8	95	495	8	4064	3.05

**D0008A****PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

**NOTES:**

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

**D0008A**

### SOIC - 1.75 mm max height

## SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



## SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
Copyright © 2022, Texas Instruments Incorporated

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Audio Amplifiers](#) category:*

*Click to view products by [Texas Instruments](#) manufacturer:*

Other Similar products are found below :

[LV3313PM-TLM-E](#) [LV47002P-E](#) [LV4924VH-TLM-H](#) [NCP2811AFCT1G](#) [NCP2890AFCT2G](#) [NCP2993FCT2G](#) [NTE1192](#) [LC75412WH-D-E](#) [TDA7385H](#) [NCP2820FCT2G](#) [STPA001](#) [TDA7563BH](#) [TS2012EIJT](#) [NCP2809BMUTXG](#) [NJW1157BFC2](#) [IS31AP4996-GRLS2-TR](#) [NCP2823BFCT1G](#) [TDA75612LV-48X](#) [TDA7850AH](#) [LA4450L-E](#) [IS31AP2036A-CLS2-TR](#) [NTE1110](#) [NTE7100](#) [NTE7114](#) [NTE7163](#) [NTE7168](#) [NTE7177](#) [NTE7178](#) [NTE7186](#) [NTE7198](#) [NTE7202](#) [NTE7217](#) [STPA001A](#) [SABRE9601K](#) [THAT1646W16-U](#) [PAM8965ZLA40-13](#) [TSDP11XX1NBGIZBX](#) [TSDP11XX1NLGXZBX](#) [NJM4580CV-TE1](#) [NJU7084R-TE1](#) [NJM4580ED-TE1](#) [TAS5720MRSMR](#) [AW8737AFRCR](#) [TDA2030](#) [TDA7265L-J11-A-T](#) [TDA7377-JSM](#) [AW88395CSR](#) [AW88266AFRCR](#) [AW87390FCR](#) [AW87339CSR](#)